



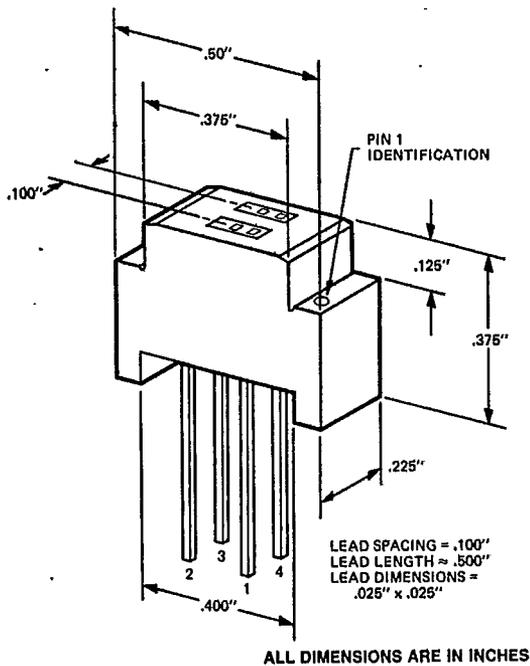
**REFLECTIVE OBJECT SENSOR**

**MSA7**

(OLD PART NO.—MCA7)

**2**

**PACKAGE DIMENSIONS**



**DESCRIPTION**

The MSA7 optoisolator consists of an infrared emitting diode and a silicon planar photodarlington. The on-axis radiation of the emitter and the on-axis response of the detector are both perpendicular to the face of the MSA7. The photodarlington responds to radiation emitted from the diode only when a reflective object or surface is in the field of view of the detector.

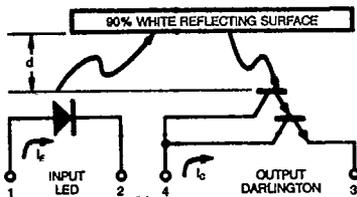
**FEATURES**

- High sensitivity
- Low cost
- High reliability

**APPLICATIONS**

- Object sensing
- End-of-tape sensing

| PIN |                           |
|-----|---------------------------|
| 1   | LED ANODE                 |
| 2   | LED CATHODE               |
| 4   | PHOTODARLINGTON COLLECTOR |
| 3   | PHOTODARLINGTON EMITTER   |



C1016

Fig. 1. Parameter Symbols

**ABSOLUTE MAXIMUM RATINGS**

|  |                |
|--|----------------|
| Storage Temperature                          | −55°C to 100°C |
| Operating Temperature                        | −55°C to 100°C |
| Lead Temperature (Soldering, 5 sec)          | 260°C          |
| Total Power Dissipation (25° Free Air Temp.) | 250 mW         |
| Derate linearly from 25°C                    | 3.3 mW/°C      |

**INPUT DIODE**

|  |           |
|--|-----------|
| Power dissipation at 25°C ambient          | 90 mW     |
| Derate linearly from 25°C                  | 1.2 mW/°C |
| Forward current                            | 60 mA     |
| Reverse voltage                            | 3 V       |
| Peak forward current (1 μs pulse, 300 pps) | 3.0 A     |

**OUTPUT DARLINGTON**

|                                   |           |
|-----------------------------------|-----------|
| Power dissipation at 25°C Ambient | 150 mW    |
| Derate linearly from 25°C         | 2.0 mW/°C |
| Collector Current                 | 25 mA     |
| Collector to emitter voltage      | 30 V      |



T-41-73  
**REFLECTIVE OBJECT SENSOR**

**ELECTRO-OPTICAL CHARACTERISTICS**  
(25°C Free Air Temperature Unless Otherwise Specified)

| CHARACTERISTIC            | SYMBOL           | MIN. | TYP. | MAX. | UNITS         | TEST CONDITIONS                                  |
|---------------------------|------------------|------|------|------|---------------|--|
| <b>INPUT DIODE</b>        |                  |      |      |      |               |  |
| Forward voltage           | $V_F$            |      | 1.25 | 1.50 | V             | $I_F=20\text{ mA}$                               |
| Reverse breakdown voltage | $BV_R$           | 3.0  | 5.5  |      | V             | $I_R=10\text{ }\mu\text{A}$                      |
| Junction capacitance      | $C_j$            |      | 50   |      | pF            | $V_F=0\text{V}$                                  |
| Reverse leakage current   | $I_R$            |      | .01  | 10   | $\mu\text{A}$ | $V_R=3.0\text{V}$                                |
| <b>OUTPUT DARLINGTON</b>  |                  |      |      |      |               |  |
| Breakdown voltage         | $BV_{CEO}$       | 30   | 55   |      | V             | $I_C=1.0\text{ mA}$<br>$I_F=0$ (NOTE 2)          |
| Reverse breakdown voltage | $BV_{ECO}$       | 5    | 7    |      | V             | $I_C=100\text{ }\mu\text{A}$<br>$I_F=0$ (NOTE 2) |
| Leakage current           | $I_{CEO}$ (dark) |      | 0.6  | 100  | nA            | $V_{CE}=5\text{V}$ (NOTE2), $I_F=0$              |

**TRANSFER CHARACTERISTICS**

| DC CHARACTERISTICS   | SYMBOL | MIN. | TYP. | MAX. | UNITS | TEST CONDITIONS  |
|----------------------|--------|------|------|------|-------|--|
| <b>COUPLED</b>       |        |      |      |      |       |  |
| DC Collector Current | $I_C$  | .050 | 1    |      | mA    | $I_F=50\text{ mA}$<br>$V_{CE}=5.0\text{V}$ (NOTE 1 & 2)<br>$d=1.0\text{ cm}$ |

**TRANSFER CHARACTERISTICS**

| AC CHARACTERISTICS   | SYMBOL     | MIN. | TYP. | MAX. | UNITS | TEST CONDITIONS                          |
|----------------------|------------|------|------|------|-------|--|
| Rise time, fall time | $t_r, t_f$ |      | 0.6  |      | mS    | $V_{CE}=5\text{V}$ $R_L=1\text{K}\Omega$ |

**TYPICAL ELECTRO-OPTICAL CHARACTERISTICS**  
( $T_A=25^\circ\text{C}$  Unless Otherwise Specified)

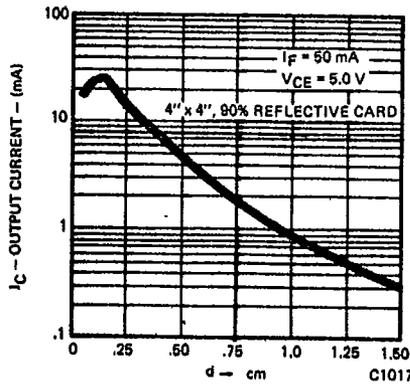


Fig. 2. Output Current vs. Distance

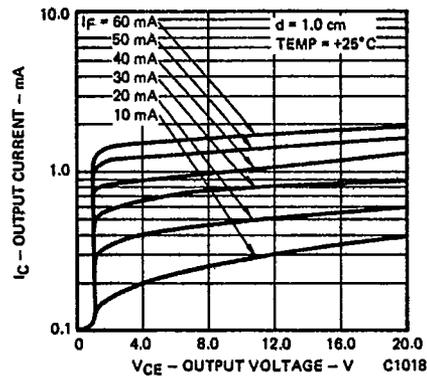


Fig. 3.  $I_C$  vs.  $V_{CE}$



REFLECTIVE OBJECT SENSOR

T-41-73



TYPICAL ELECTRO-OPTICAL CHARACTERISTIC CURVES

( $T_A = 25^\circ\text{C}$  Unless Otherwise Specified) (Cont'd)

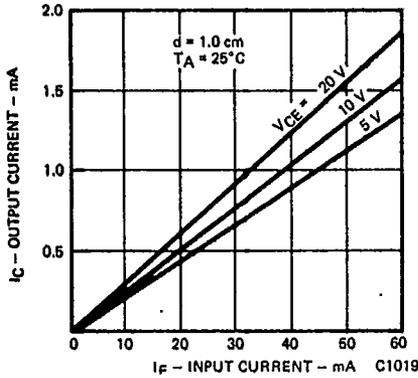


Fig. 4.  $I_C$  vs.  $I_F$

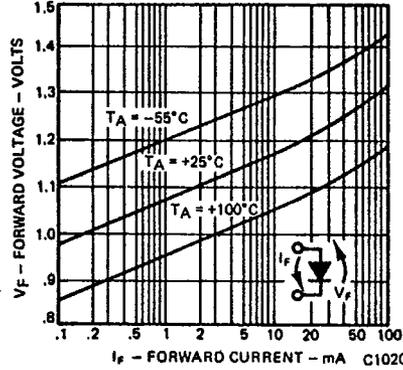


Fig. 5. Forward Voltage vs. Forward Current

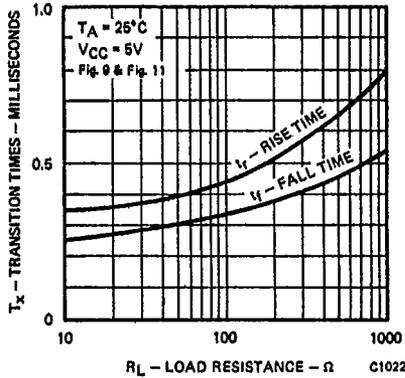


Fig. 6. Non-Saturated Rise and Fall Times vs. Load Resistance

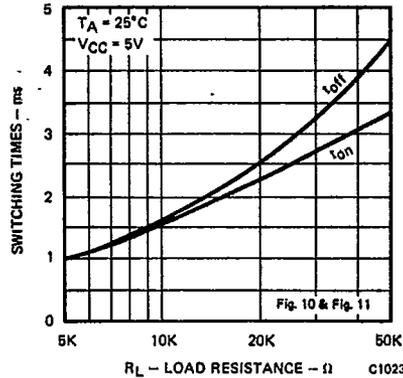


Fig. 7. Saturated Switching Times vs. Load Resistance

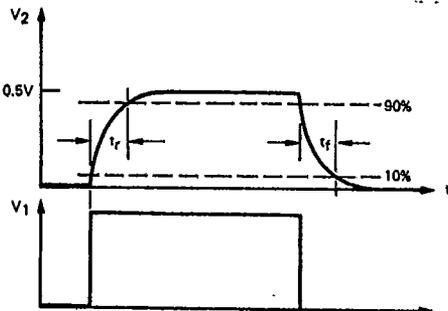


Fig. 8. Non-Saturated Switching Waveforms

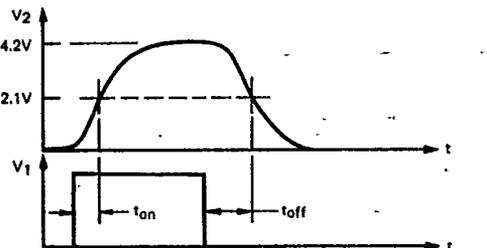


Fig. 9. Saturated Switching Waveforms



REFLECTIVE OBJECT SENSOR

T-41-73

**TYPICAL ELECTRO-OPTICAL CHARACTERISTIC CURVES**

( $T_A = 25^\circ\text{C}$  Unless Otherwise Specified) (Cont'd)

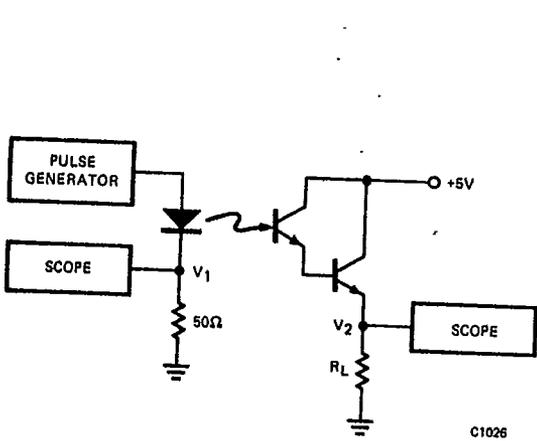


Fig. 10. Circuit for Testing Switching Parameters

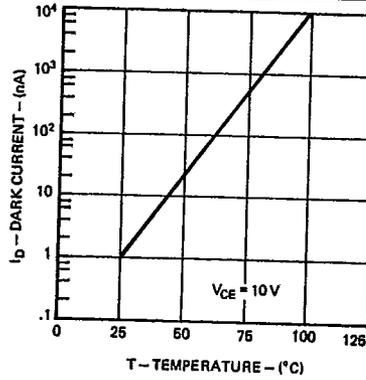
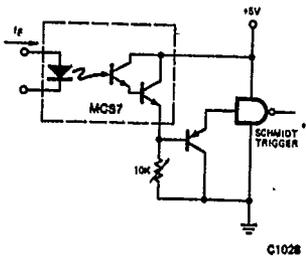
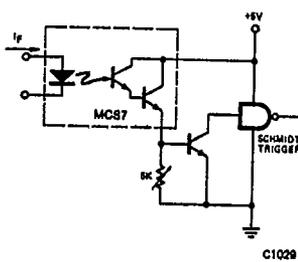


Fig. 11. Dark Current vs. Temperature

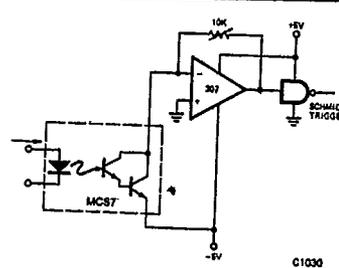
**CIRCUITS TO INTERFACE THE MCS7 WITH 5V LOGIC**



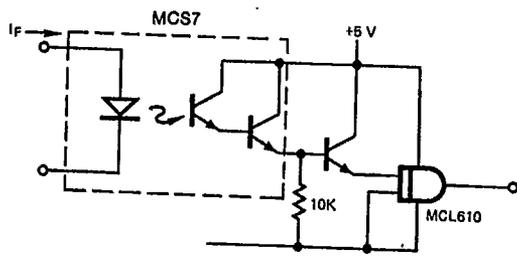
Circuit 1  
Normally High Output



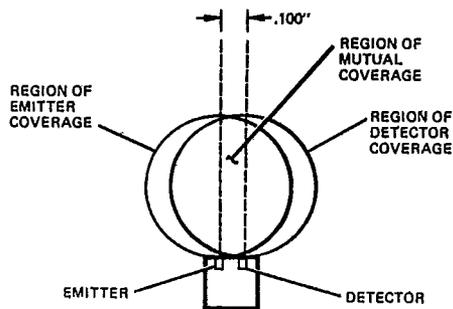
Circuit 2  
Normally Low Output



Circuit 3  
Comparator Driver



Circuit 4  
Booster Drive to Logic Isolator



Spatial Distribution of Maximum Sensitivity

MSA7



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T-41-73

2

**NOTES**

1. Photo current is obtained from a  $4.0'' \times 4.0''$ , 90% white surface placed at a distance of 1.0 cm from the surface of the MCA7.
2. Measured with radiation flux intensity of less than  $0.1 \mu\text{W}/\text{cm}^2$  (dark condition) over the spectrum from 0.1 micron to 1.5 microns.
3. Measured at typical factory ambient of 150 foot-candles (150 lamberts per square foot).